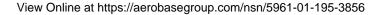
NSN 5961-01-195-3856

Transistor - Page 1 of 1



Inclosure Material:

Metal

Terminal Length:

0.312 inches

Overall Height:

Between 0.280 inches and 0.328 inches

Overall Diameter:

Between 0.715 inches and 0.740 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage, dc and 40.0 collector to emitter voltage, dc and 20.0 emitter to base voltage, dc

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 10.00 amperes zero-gate-voltage source current blank and 1.00 amperes source cutoff current and 2.00 amperes zero-gate-voltage source current of standard range

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0